

Quad 2-Input OR Gate MM74HC32

General Description

The MM74HC32 OR gates utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits.

All gates have buffered outputs providing high noise immunity and the ability to drive 10 LS–TTL loads. The 74HC logic family is functionally as well as pin–out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to $V_{\rm CC}$ and ground.

Features

- Typical Propagation Delay: 10 ns
 Wide Power Supply Range: 2 V 6 V
- Low Quiescent Current: 20 μA maximum (74HC Series)
- Low Input Current: 1 μA Maximum
- Fanout of 10 LS-TTL Loads
- These Devices are Pb-Free, Halide Free and are RoHS Compliant

Connection Diagram

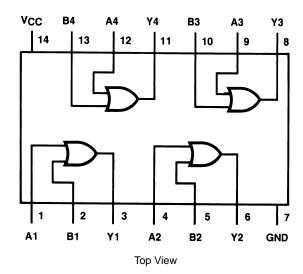


Figure 1. Pin Assignments for SOIC and TSSOP

Logic Diagram

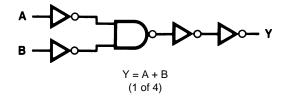


Figure 2. Logic Diagram

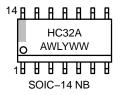
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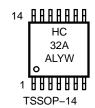






MARKING DIAGRAM





HC32A = Specific Device Code A = Assembly Location

WL, L = Wafer Lot Y = Year WW, W = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

MM74HC32

ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol		Rating			
V _{CC}	Supply Voltage		−0.5 to +7.0 V		
V _{IN}	DC Input Voltage		–0.5 to V _{CC} + 0.5 V		
V _{OUT}	DC Output Voltage	DC Output Voltage			
I _{IK} , I _{OK}	Clamp Diode Current	±20 mA			
l _{out}	DC Output Current, per Pin	±25 mA			
I _{CC}	DC V _{CC} or GND Current, per Pin	±50 mA			
T _{STG}	Storage Temperature Range		−65°C to +150°C		
P _D	Power Dissipation Note 2		600 mW		
		S.O. Package Only	500 mW		
TL	Lead Temperature (Soldering 10 S	Seconds)	260°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Unless otherwise specified all voltages are referenced to ground.

- 2. Power Dissipation temperature derating plastic "N" package: –12 mW/°C from 65°C to 85°C.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V _{CC}	Supply Voltage	2	6	V	
V _{IN} , V _{OUT}	DC Input or Output Voltage	0	V _{CC}	V	
T _A	Operating Temperature Range			+85	°C
t _r , t _f	Input Rise or Fall Times V _{CC} = 2.0 V		_	1000	ns
		V _{CC} = 4.5 V	_	500	ns
		V _{CC} = 6.0 V	_	400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

MM74HC32

DC CHARACTERISTICS (Note 3)

				T _A =	25°C	$T_A = -40^{\circ}C$ to $85^{\circ}C$	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур	Gua	aranteed Limits	Unit
V_{IH}	Minimum HIGH Level Input Voltage	2.0		-	1.5	1.5	V
		4.5		-	3.15	3.15	
		6.0		-	4.2	4.2	
V_{IL}	Maximum LOW Level Input Voltage	2.0		-	0.5	0.5	V
		4.5		-	1.35	1.35	
		6.0		-	1.8	1.8	
V _{OH}	Minimum HIGH Level Output Voltage	2.0	$V_{IN} = V_{IH}$ or V_{IL} ,	2.0	1.9	1.9	V
		4.5	I _{OUT} ≤ 20 μA	4.5	4.4	4.4	
		6.0		6.0	5.9	5.9	
		4.5	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 4.0 \text{ mA}$	4.2	3.98	3.84	
		6.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 5.2 \text{ mA}$	5.2	5.48	5.34	
V _{OL}	Maximum LOW Level Output Voltage	2.0	$V_{IN} = V_{IH}$ or V_{IL} ,	0	0.1	0.1	V
		4.5	I _{OUT} ≤ 20 μA	0	0.1	0.1	
		6.0		0	0.1	0.1	
		4.5	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 4.0 \text{ mA}$	0.2	0.26	0.33	
		6.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 5.2 \text{ mA}$	0.2	0.26	0.33	
I _{IN}	Maximum Input Current	6.0	V _{IN} = V _{CC} or GND	-	±0.1	±1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current	6.0	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0 \mu A$	-	2.0	20	μА

^{3.} For a power supply of 5 V $\pm 10\%$ the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used.

AC CHARACTERISTICS (V_{CC} = 5 V, T_A = 25°C, C_L = 15 pF, t_r = t_f = 6 ns)

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Unit
t _{PHL} , t _{PLH}	Maximum Propagation Delay		10	18	ns

AC CHARACTERISTICS (V_{CC} = 2.0 V to 6.0 V, C_L = 50 pF, t_r = t_f = 6 ns (unless otherwise specified))

				T _A = 25°C		$T_A = -40^{\circ}C$ to $85^{\circ}C$	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур	Guaranteed Limits		Unit
t _{PHL} , t _{PLH}	Maximum Propagation Delay	2.0		30	100	125	ns
		4.5		12	20	25	
		6.0		9	17	21	
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time	2.0		30	75	95	ns
		4.5		8	15	19	
		6.0		7	13	16	
C _{PD}	Power Dissipation Capacitance (Note 4)		(per gate)	50	_	-	pF
C _{IN}	Maximum Input Capacitance			5	10	10	pF

^{4.} C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.

MM74HC32

ORDERING INFORMATION

Part Number	Package	Shipping [†]
MM74HC32M	SOIC-14, Case 751A-03 (Pb-Free, Halide-Free)	55 Units / Tube
MM74HC32MTC	TSSOP-14, Case 948G-01 (Pb-Free, Halide Free)	96 Units / Tube
MM74HC32MX	SOIC-14, Case 751EF (Pb-Free, Halide-Free)	2500 Units / Tape & Reel
MM74HC32MTCX	TSSOP-14, Case 948G-01 (Pb-Free, Halide Free)	2500 Units / Tape & Reel

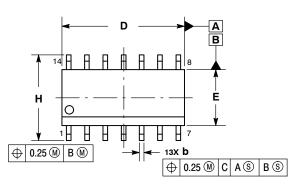
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

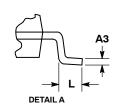


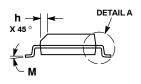


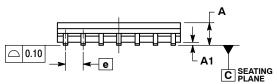
SOIC-14 NB CASE 751A-03 ISSUE L

DATE 03 FEB 2016









GENERIC MARKING DIAGRAM*

MIN MAX

0.050 BSC

0.068

0.019

0.054

0.25 0.004 0.010

0.25 0.008 0.010

0.50 0.010 0.019

1.25 0.016 0.049

0.49 0.014

8.55 8.75 0.337 0.344 3.80 4.00 0.150 0.157

NOTES:
1. DIMENSIONING AND TOLERANCING PER

5. MAXIMUM MOLD PROTRUSION 0.15 PER

MILLIMETERS MIN MAX

1.27 BSC

0.19

0.25

0.40

SIDE

Α

A1 0.10

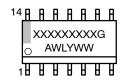
АЗ

b 0.35

D 8.55 E 3.80

e H h

ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS.
DIMENSION b DOES NOT INCLUDE DAMBAR
PROTRUSION. ALLOWABLE PROTRUSION
SHALL BE 0.13 TOTAL IN EXCESS OF AT
MAXIMUM MATERIAL CONDITION.
DIMENSIONS D AND E DO NOT INCLUDE
MOLD PROTRUSIONS.



XXXXX = Specific Device Code A = Assembly Location

WL = Wafer Lot
 Y = Year
 WW = Work Week
 G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DIMENSIONS: MILLIMETERS

STYLES ON PAGE 2

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SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

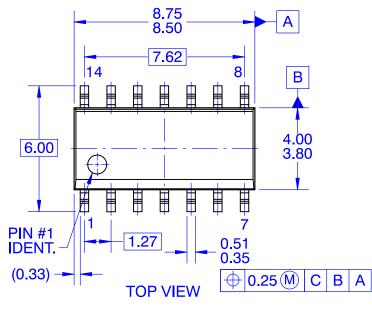
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STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

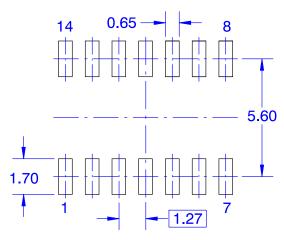
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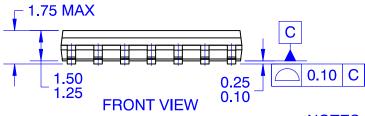


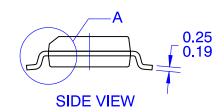
DATE 30 SEP 2016





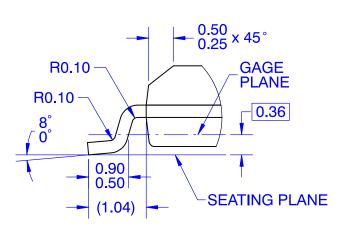
LAND PATTERN RECOMMENDATION





NOTES:

- A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C
 B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS
- LAND PATTERN STANDARD: SOIC127P600X145-14M
- E. CONFORMS TO ASME Y14.5M, 2009



DETAIL A SCALE 16:1

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